Name	
Date	
Instructor	



Current Source and Current Mirror Circuits

OBJECTIVE

To calculate and measure DC voltages in current source and current mirror circuits.

EQUIPMENT REQUIRED

Instruments

Oscilloscope

DMM

Function generator

DC supply

Components

Resistors

- $(1) 20-\Omega$
- (1) $51-\Omega$
- (1) $82-\Omega$
- (1) $100-\Omega$
- (1) $150-\Omega$
- (2) 1.2-kΩ
- (1) 4.3-kΩ
- $(1) 5.1-k\Omega$
- (1) $7.5-k\Omega$
- (1) 10-kΩ

Transistors

- (3) 2N3904, or equivalent npn transistor
- (1) 2N3823, or equivalent JFET n-channel transistor

EQUIPMENT ISSUED

<u>Item</u>	Laboratory serial no.
DC power supply	
Function generator	
Oscilloscope	
DMM	

RÉSUMÉ OF THEORY

Current source and current mirror circuits are part of many types of linear integrated circuits. This experiment will provide building and testing a few types of each circuit.

Current Source: Fig. 24.1 shows a simple form of current source using a JFET biased to operate at its drain-source saturation current. Regardless of the load R_L (within practical limits) the current through load R_L will be set by the JFET device:

Current source

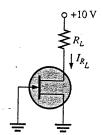


Figure 24-1

$$I_L = I_{DSS} \tag{24.1}$$

A BJT current source circuit is shown in Fig. 24.2. The base voltage is approximately set by

$$V_B = \frac{R_1}{R_1 + R_2} (-V_{EE})$$

The emitter voltage is then

$$V_E = V_B - 0.7 \text{ V}$$

with the emitter current then

$$I_{R_E} = \frac{V_E - V_{EE}}{R_E} = I_{R_L} \tag{24.2}$$

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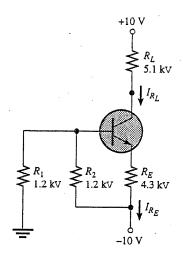


Figure 24-2

Current Mirror: The circuit of a Fig. 24.3 is a current mirror, in which the current set through resistor R_x is mirrored through the load

$$I_x = \frac{V_{CC} - V_{BE}}{R_x} = I_{R_L}$$
 (24.3)

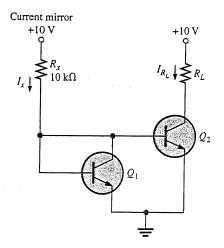


Figure 24-3

The circuit of Fig. 24.4 shows how a current mirror can provide the same current to a number of loads. The mirrored current set through resistor R_x and mirrored through both loads is

$$I_{R_x} = \frac{V_{CC} - V_{BE}}{R_X} = I_{R_2} = I_{R_3}$$
 (24.4)

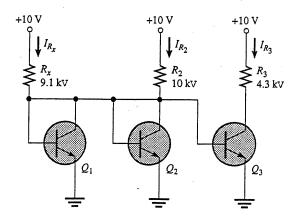


Figure 24-4

PROCEDURE

Part 1. JFET Current Source

a. Wire up the circuit of Fig. 24.1. Use $R_L = 51$. Measure and record the drain-source voltage.

$$V_{DS}$$
 (measured) =

b. Using the voltage measured in step 1(a), calculate the load current.

$$I_{R_L} = \frac{V_{DD} - V_{DS}}{R_L}$$

$$I_{R_L} = \underline{\hspace{1cm}}$$

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c. Replace R_L with resistors as listed in Table 24.1, and repeat steps $1(\mathbf{a})$ and $1(\mathbf{b})$.

TABLE 24.1

R_L	20 Ω	51 Ω	<i>82</i> Ω	100 Ω	150 Ω
V_{DS}					
I_{R_L}					

Part 2.	BJT	Current	Source
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	Calculate 24.2.	the	${\tt current}\ I_{R_L}$	through	the	load	in	the	circuit	of	Fig	
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	$I_{R_{I_{\cdot}}}$ (calculated)	=
	u		
e up the circuit of F	ig. 24.2. Measure	and record	the following

b.	Wire up th	e circuit	of Fig.	24.2.	Measure	and	record	the	following
	voltages.								J

c. Calculate the emitter current and the current through the load.

$$I_{R_E} =$$
 $I_{R_L} =$

d. Replace R_L with resistors listed in Table 24.2 and repeat steps 2(a) through 2(c).

TABLE 24.2

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R_L	3.6 kΩ	4.3 kΩ	5.1 kΩ	7.5 kΩ	
V_E				-	-
V_C					-
I _{RE}					
I_{R_L}					

Part 3. Current Mirror

a. Calculate the mirror current in the circuit of Fig. 24.3.

I_x	(calcula	ated) =	

b.	Wire up	the	circuit	of Fig.	24.3	and	measure
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V_{B_1} (measured) =	& ·
V_{C_2} (measured) =	\$-
$I_x =$	
$I_{R_L} = 1$	

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c. Change R_L to 3.6 k Ω and repeat steps 3(a) and 3(b).

$$I_x$$
 (calculated) = V_{B_1} (measured) = V_{C_2} (measured) = I_x = I_{R_L} =

Part 4. Multiple Current Mirrors

a. Calculate the mirror current in the circuit of Fig. 24.4.

$$V_{B_1} \, (\text{measured}) = \\ V_{C_2} \, (\text{measured}) = \\ \\ V_{C_3} \, (\text{measured}) = \\ \\ I_{R_x} = \\ \\ I_{R_2} = \\ \\ I_{R_3} =$$

c. Change R_L to 3.6 k Ω and repeat steps 4(a) and 4(b).

I_{R_r} (calculated) =	
V_{B_1} (measured) =	
V_{C_2} (measured) =	
$V_{C_3}^{2}$ (measured) =	
$I_{R_x} =$	
I_{R_2} =	
$I_{R_3} =$	

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